



“XE20-200A” Series (HC/ACMOS), 5.0 VDC High Reliability Hybrid Microcircuit Crystal Oscillators

Features

- Ruggedized 4 Point Crystal Mount
- Tristate Output Option
- Radiation Tolerant to 10K Rads
- 100% Screening Options
- Low Phase Noise
- Hermetically Sealed Metal Package
- ECCN: EAR99

Applications

- High Shock & Vibration Applications
- Navigation Systems
- Aerospace Instrumentation
- Benign Space Applications
- Gun Launched Munitions

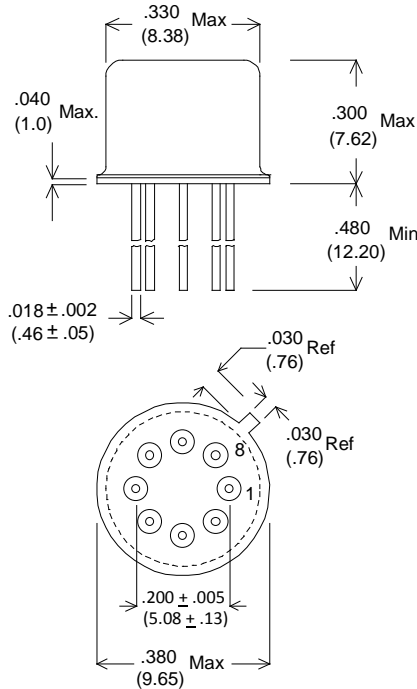
Package Specifications & Outline:

- Header & Leads Material: Kovar
- Cover Material: Nickel
- Seal: Hermetic – Resistance Welded
- Weight: 1.0 Gms typical, 1.2 Gms Max.
- Thermal Resistance, Junction to Case (θ_{JC}): 30 °C / Watt
- Lead Soldering, Temp./Time: 260 °C, 10 Secs. Max.

Header & Lead Finish: 50 to 80 μ inches gold over
100 to 250 μ inches nickel

Hot Solder Tinning per MIL-PRF-55310 is optional at additional cost.

Contact Xsis Electronics at xisis@xisis.com for any special requirements.



| LEAD# | FUNCTION |
|------------|----------------|
| 3 | E/D (Optional) |
| 4 | GND/CASE |
| 5 | OUTPUT |
| 8 | VDD |
| All Others | N/C |

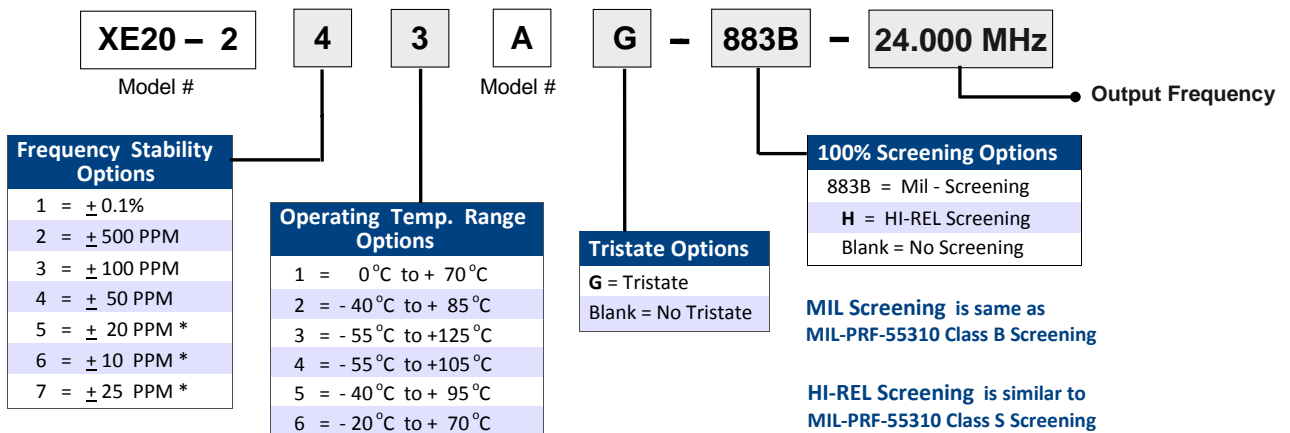
Dimensions: Inches (mm)

E/D (Enable/Disable) Input: A “Low” level at the input disables the Output into a high impedance state.

E/D Input has internal pull-up. It can be left floating or connected to Vdd.

ORDERING INFORMATION (Please build your part number from options below) :

P/N EXAMPLE: XE20 – 243AG – 883B - 24.000 MHz = 5.0V HC/ACMOS, ± 50 PPM over -55 °C to +125 °C, Tristate Output, 883B Screening, 24.000 MHz



* Frequency Stability Options 5, 6 & 7 are not available for all operating temperature ranges.



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Electrical Specifications:

| Parameter | Specification Limits |
|---|--|
| Output Frequency Range | 400 KHz - 100 MHz |
| Frequency Accuracy at +25 °C | ± 15 PPM |
| Frequency Stability Vs Temperature | See Ordering Information on Page 1 |
| Operating Temperature Range | See Ordering Information on Page 1 |
| Supply Voltage (Vdd) | + 5 VDC ± 10% |
| Input Current (no Load) | 400 KHz - 5 MHz 10 mA Max. 5.1 MHz - 20 MHz 20 mA Max. 20.1 MHz - 40 MHz 30 mA Max. 40.1 MHz - 60 MHz 40 mA Max. 60.1 MHz - 100 MHz 60 mA Max. |
| Output Waveform | Square Wave, HC/ACMOS Compatible |
| Output Duty Cycle (at 50% Output Level) | < 30 MHz 55/45% Max. ≥ 30 MHz 60/40% Max. |
| Output High Level | 0.9 Vdd Min. |
| Output Low Level | 0.1 Vdd Max. |
| Output Load | 10 KΩ // 15 pf |
| Rise & Fall Times (Typical Load) | < 30 MHz 6 nS Max. ≥ 30 MHz 3 nS Max. (10% to 90% Output Levels) |
| Enable/Disable (E/D) | E/D Input ≥ 3.5V or Open : Normal Output E/D Input ≤ 0.8V: High Impedance |
| Start-Up Time | 5 mS Max. |
| Phase Jitter (10 KHz - 20 MHz Integrated) | 0.15 pS rms Typical |
| Freq. Stability Vs Supply Voltage | ± 4 PPM Max. for ± 10% change in Supply Voltage |
| Aging at 70 °C | ± 3 PPM Max. first year, ± 2 PPM Max. per year thereafter |
| Absolute Maximum Applied Voltage | + 7VDC |
| Storage Temperature | -65 °C to +125 °C |

For special requirements, such as, tighter output symmetry, faster start-up time, PIND screening, etc., please contact Xsis Electronics at xisis@xisis.com or call us at 913-631-0448.



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Packaging: ESD protective conductive foam tray

Thermal Characteristics:

Junction to case Thermal Constant (θ_{JC}): 30 °C / Watt

Junction to Ambient (Device floating in free air) Thermal Constant (θ_{JA}): 135 °C / Watt

Hi-Rel Screening:

When HI-REL option is selected, Xsis Oscillators are subjected to 100% screening similar to Class “S” screening in accordance with MIL-PRF-55310. Refer to www.xsis.com for additional details about HI-REL screening.

Typical Phase Noise (dbc/Hz):

| Output Frequency | 10 Hz | 100 Hz | 1 KHz | 10 KHz | 100 KHz | 1 MHz |
|------------------|-------|--------|-------|--------|---------|-------|
| 10 MHz | -109 | -140 | -157 | -162 | -163 | -164 |
| 25 MHz | -100 | -127 | -151 | -158 | -160 | -162 |
| 50 MHz | -89 | -117 | -148 | -157 | -159 | -160 |
| 96 MHz | -80 | -107 | -139 | -151 | -156 | -158 |
| 100 MHz | -77 | -104 | -133 | -145 | -151 | -155 |

Environmental Specifications:

XE20-200A series oscillators are designed to meet or exceed the Environmental tests specified below. Customized screening and environmental testing are also available to meet your special requirements.

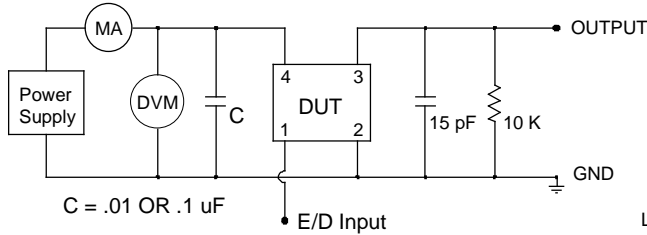
| Test | Test Conditions |
|------------------------------|---|
| Vibration | 0.06” DA, 30 G peak, 10 - 2000 Hz, MIL-STD-202, Method 204, Cond. G |
| Shock | 1500 G, 0.5 mS, half-Sine, MIL-STD-883, Method 2002, Cond. B |
| Temperature Cycling | MIL-STD-883, Method 1010, Cond. C |
| Thermal Shock | MIL-STD-202, Method 107, Cond. B |
| Seal (Fine and Gross) | MIL-STD-883, Method 1014 Cond. A & C |
| Burn-in | 160 Hours, 125 °C, Nominal Supply Voltage & Load |
| Frequency Aging | 30 days at 70 °C, \pm 1.5 PPM Max. |
| Altitude | MIL-STD-202, Method 105, Cond. C |
| Constant Acceleration | MIL-STD-883, Method 2001, 5000 G |
| Moisture Resistance | MIL-STD-202, Method 106, Vibration Sub Cycle Omitted |
| Solderability | MIL-STD-202, Method 208 |
| Resistance to Soldering Heat | MIL-STD-202, Method 210, Cond B. or C as applicable |
| Resistance to Solvents | MIL-STD-202, Method 215 |
| Internal Water Vapor Content | MIL-STD-883, Method 1018 |
| ESD Classification | MIL-STD-883, Method 3015, Class 1C, HBM 1000 to 1999 |
| Moisture Sensitivity Level | J-STD-020, MSL=1 |



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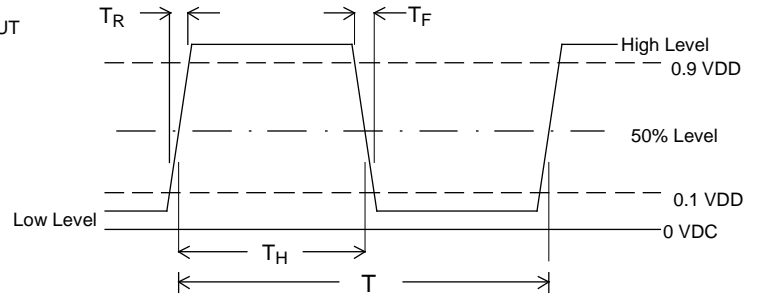
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HCMOS Test Circuit



E/D (Enable/Disable) Input has an internal pull-up resistor. It can be left floating or connected to Vdd.

HCMOS Output Waveform



$$\text{Symmetry} = \frac{T_H}{T} \times 100 \%$$

Typical Freq. Stability Vs. Temperature

